Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material: Metal Overall Length: 0.260 inches Terminal Length: 1.500 inches Overall Diameter: 0.370 inches Internal Configuration: Junction contact Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-5 Mounting Method: Terminal Terminal Terminal Circle Diameter: 0.200 inches Features Provided: Hermetically sealed case Semiconductor Material: Silicon Voltage Rating In Volts Per Characteristic: 25.0 repetitive peak off-state voltage Current Rating Per Characteristic: 1.60 amperes forward current, total rms nanoamperes Maximum Operating Tempurature Per Measurement Point: 125.0 degrees celsius case Special Features: Internal junction configuration arrangement ppn
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Maximum Operating Tempurature Per Measurement Point: 125.0 degrees celsius case Special Features:
125.0 degrees celsius case Special Features:
Special Features:
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Internal junction configuration arrangement pnpn
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
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